

# Rectifiers: Half & Full-Wave Circuits

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## Introduction

Half-Wave Rectifier

## Fullwave Rectifier

Full-Wave Rectifier: 2 Diodes

Full-Wave Rectifier: 4 Diodes

## Other applications

Diodes driven by light..

# Introduction

- ▶ Rectifiers are a key application of diodes that we found any other day.
- ▶ A basic circuit rectifier converts an ac signal into a pulsating dc voltage signal. At the end of the process, a filter is required to eliminate any traces from the ac signal and to keep it as smooth as possible.
- ▶ Almost whole devices that are plugged requires a rectifier to convert 120 V @ 60 Hz into a broad spectrum of dc voltages

# Introduction

- ▶ Only one diode is used within a half-wave rectifier
- ▶ An oscillatory source  $v_1 = V_P \sin \omega t$  is connected to a diode  $D_1$  and a load resistor  $R_L$  in series
- ▶ In the first part of the cycle, for which  $v_1 > 0$ , the source bias the diode  $D_1$  and a current passes through it in the forward direction. As for the second half of the cycle,  $v_1 < 0$ . As a negative current is not allowed in the diode (unless breakdown), it opens or turn off. Both states are shown

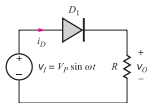


Figure 3.42 Half-wave rectifier circuit.

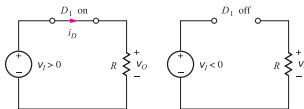
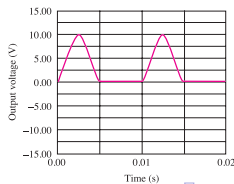
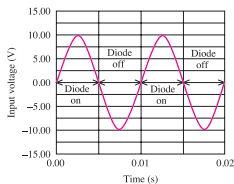


Figure 3.43 Ideal diode models for the two half-wave rectifier states.



# Introduction

- ▶ Another configuration a bit more complex but a bit more realistic

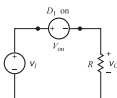


Figure 3.45 CVD model for the rectifier on state.

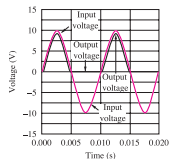


Figure 3.46 Half-wave rectifier output voltage with  $V_P = 10$  V and  $V_{on} = 0.7$  V.

In figure in black line, shows that the output signal is smaller than the input, it is due to the diode bias

$$v_o = (V_P \sin \omega t) - V_{on}$$

- ▶ The output voltage are zero on the off state interval. The input and output signals for the half rectifier that includes the  $V_{on}$  effect as  $V_P=10$  V and  $V_{on}=0.7$  V

# Introduction

- ▶ In quite a few applications a transformer is used to convert ac signal to a desired dc level
- ▶ The unfiltered output signals cannot be used for nowadays applications as such, due to it requires specific characteristics
- ▶ A filter capacitor can be added to filter the the output of the circuit

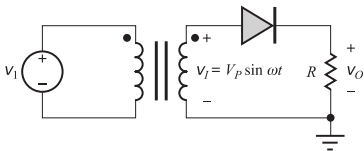


Figure 3.47 Transformer-driven half-wave rectifier.

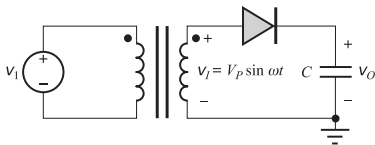


Figure 3.48 Rectifier with capacitor load (peak detector).

# Rectified Filter Capacitor

- ▶ The peak detector circuit or filter capacitor circuit, considers a capacitor as load than a resistor.
- ▶ When the source is on, the diode is biased and the capacitor charges to the source minus  $v_D$
- ▶ Once at peak of the input voltage signal, the current through the diode follow a reverse path due to  $i_D = C[d(v_1 - v_{on})dt] < 0$
- ▶ As a consequence, the diode is disconnected and the capacitor remains charged
- ▶ As there is no way for the capacitor to discharge it remains constant

$$V_{dc} = V_P - V_{on}$$

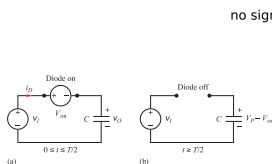


Figure 3.49 Peak-detector circuit models (constant voltage drop model). (a) The diode is on for  $0 \leq t \leq T/2$ . (b) The diode is off for  $t \geq T/2$ .

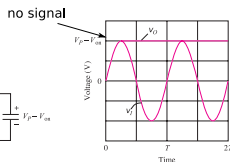


Figure 3.50 Input and output waveforms for the peak-detector circuit.

# Rectified RC Filter

- ▶ We need to use the energy as a dc signal, this is why, we need to add a resistive load 'R' to recover the energy stored
- ▶ now there is a way to discharge the capacitor while the diode is not working
- ▶ We consider 'C' initially discharged. For the initial cycle, the diodes is bias and C is charged. While in inverse current occurs at peak, the diode cuts off and C discharges through the resistor R
- ▶ Discharges continues until  $v_t - v_{on}$  is larger than the output voltage  $v_0$  that occurs near the peak of the follow cycle.

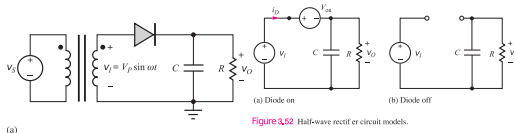


Figure 3.52 Half-wave rectifier circuit models.

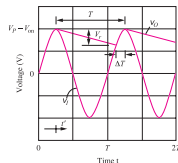


Figure 3.53 Input and output voltage waveforms for the half-wave rectifier circuit.



## Rectified RC filter

- ▶ As the output voltage is not constant anymore as in the peak detector, it has a ripple voltage  $V_r$  and the diode only conducts for a short period of time  $\Delta T$  during each cycle.  $\Delta T$  is known as the conduction interval and it equivalent angle  $\theta_c$ , where  $\theta_c = \omega \Delta T$
- ▶ By considering a rather small ripple  $\Delta T \ll T$ , ripple voltage is defined as:

$$V_r \approx \frac{V_P - V_{on}}{R} \frac{T}{C}$$

- ▶ by considering that C is discharged by a constant current, the dc current is defined as:

$$I_{dc} = \frac{V_P - V_{on}}{R}$$

- ▶ For a finite time T, if we want to discharge C, we've

$$\Delta V = \frac{I_{dc}}{C} T$$

# Rectified Filter Capacitor

- ▶ A nonzero current is present in the diode for a small fraction of time  $T$ . in contrast, an almost constant dc current is flowing from C towards the load.
- ▶ Whole current deliverately submitted to the load, must be replenished by the current through the diode during the rather small period of time  $\Delta T$ , that produces high peak diode currents

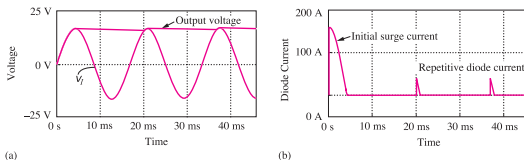


Figure 3.54 SPICE simulation of the half-wave rectifier circuit. (a) Voltage waveforms (b) Diode current.

- ▶ the total charge supplied and consumed by the system is defined as:

$$Q = I_P \frac{\Delta T}{2} = I_{dc} T \Leftrightarrow I_P = I_{dc} \frac{2T}{\Delta T}$$

# Key an basic applications

- ▶ Indeed it is possible for a diode to conduct in the negative half cycle of the transformer
- ▶ the only thing that we need to do is fulfill a few conditions such as

$$v_{dc} = -(V_P - V_{on})$$

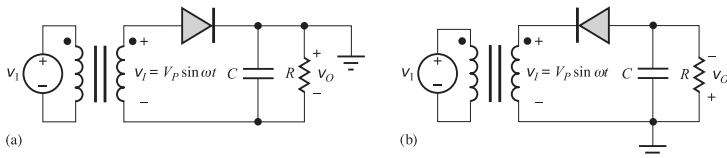


Figure 3.57 Half-wave rectifier circuits that develop negative output voltages.

# Introduction

- ▶ The discharge of the capacitor goes by half and uses the half of the filter capacitance to achieve the desired ripple
- ▶ This configuration uses a tap centered transformer that generates 2 similar voltages equal in amplitude but out of phase by  $180^\circ$
- ▶ By using voltage  $v_1$  applied to the anode of  $D_1$  and  $-v_1$  applied to  $D_2$ . Each diode forms a half wave rectifier operating each one in a different cycle of the inner waveform.

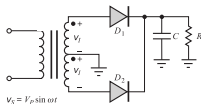


Figure 3.58 Full-wave rectifier circuit using two diodes and a center-tapped transformer. This circuit produces a positive output voltage.

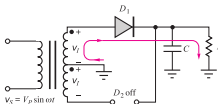


Figure 3.59 Equivalent circuit for  $v_1 > 0$ .

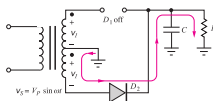


Figure 3.60 Equivalent circuit for  $v_1 < 0$ .

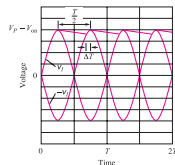


Figure 3.61 Voltage waveforms for the full-wave rectifier.

# Introduction

- ▶ The load “RC” receives two current pulses per cycle and the discharge capacitor time is reduced by half
- ▶ In a similar way as for the half-wave rectifier a few conditions are required such as:

$$\begin{aligned}V_{dc} &= V_P - V_{on} \\V_r &= \frac{V_P - V_{on}}{R} \frac{T}{2C} \\ \Delta T &= \frac{1}{\omega} \sqrt{\frac{T}{RC} \frac{V_P - V_{on}}{V_P}} = \frac{1}{\omega} \sqrt{\frac{2V_P}{V_P}} \\ \theta_c &= \omega \Delta T = \sqrt{\frac{2V_P}{V_P}} \\ I_P &= I_{dc} \frac{T}{\Delta T} \\ PIV &= 2V_P\end{aligned}$$

# Introduction

- ▶ Basically, it is the same, with a simple difference that a central tapered transformer is not needed
- ▶ Operation is similar as before, by biasing the diodes  $D_2$  &  $D_4$  a positive cycle passes through while for the negative, diodes  $D_1$  &  $D_3$  are biased in inverse and allows the wave to pass through.

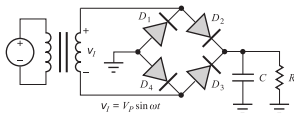


Figure 3.63 Full-wave bridge rectifier circuit with positive output voltage.

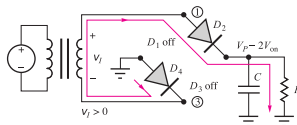


Figure 3.64 Full-wave bridge rectifier circuit for  $V_i > 0$ .

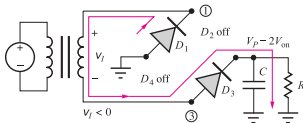


Figure 3.65 Full-wave bridge rectifier circuit for  $V_i < 0$ .

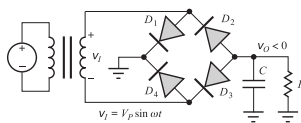


Figure 3.66 Full-wave bridge rectifier circuit with  $V_o < 0$ .

## Photo – Diodes and Detectors

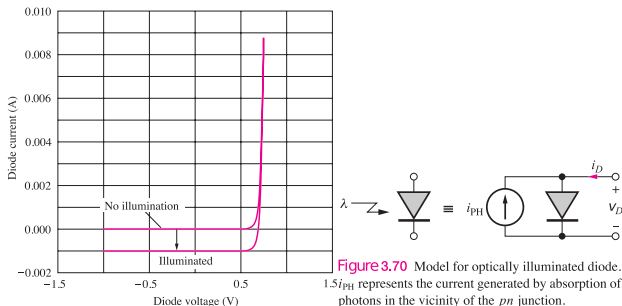
- ▶ If PN region is illuminated (give enough eV) at high frequency, photons can provide enough energy to  $e^-$  to jump in the semiconductor bandgap creating  $e^-/h^+$  pairs
- ▶ For photon absorption, it must have an initial energy  $E_P$  that is larger than the semiconductor bandgap

$$E_P = h\nu = \frac{hc}{\lambda} \geq E_G$$

where  $h$  = Planck's constant ( $6.626 \times 10^{-34}$  J · s),  $\nu$  = frequency of optical illumination  $\lambda$  = wavelength of optical illumination  $c$  = velocity of light ( $3 \times 10^8$  m/s)

# Photo – Diodes and Detectors

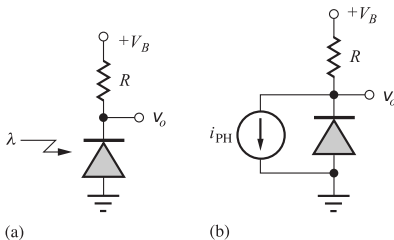
- ▶  $i - v$  characteristics with/without illumination appear in figure
- ▶ photon absorption creates another current crossing the pn junction that is modeled as a current source in parallel with the pn junction





# Photo – Diodes and Detectors

- ▶ It is possible to convert the incident optical signal into an electrical one by using an array called photodetector circuit
- ▶ Diode in reverse-biased to, due to cascade process, enhance the width of the  $\vec{E}$  at SCR
- ▶ The current generated  $i_{PH}$  will flow through R and produce a voltage according to:  $v_o = i_{PH}R$



**Figure 3.71** Basic photodetector circuit (a) and model (b).

# Solar Cell

- ▶ According to the photodetector principle, the optical illumination is constant, ergo a dc current is generated
- ▶ The milestone is to obtain as much energy as possible from the cell
- ▶ In plot the short circuit  $I_{SC}$ , open circuit voltage  $V_{OC}$  and maximum power  $P_{max}$
- ▶  $I_{SC}$  represents whole the current that the cell can deliver and  $V_{OC}$  is the voltage across the open circuited cell when the photocurrent is passing in to the internal pn
- ▶ In order to give the energy from the solar cell toward a load system,  $I_C \times V_C$  should be to operate at first quadrant

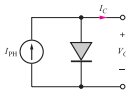


Figure 3.72 pn Diode under steady-state illumination as a solar cell.

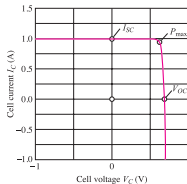


Figure 3.73 Terminal characteristics for a pn junction solar cell.

# LEDs

- ▶ By recombining process of  $e^-$  &  $h^+$  rather than by generation of carriers produces a LED
- ▶ When an  $e^-$  &  $h^+$  recombine and energy equal to the semiconductor bandgap is released as a photon
- ▶ This process occurs in forward-biased pn junction diode
- ▶ in Si, the recombination process also includes the interaction between photons and phonons
- ▶ Optical emission in Si is not efficient as for GaAs,  $\text{GaIn}_{1-x}\text{As}_x$  and  $\text{GaIn}_{1-x}\text{P}_x$
- ▶ LEDs in those compounds provide a visible illumination and the output color comes from the fraction of As or P in the material